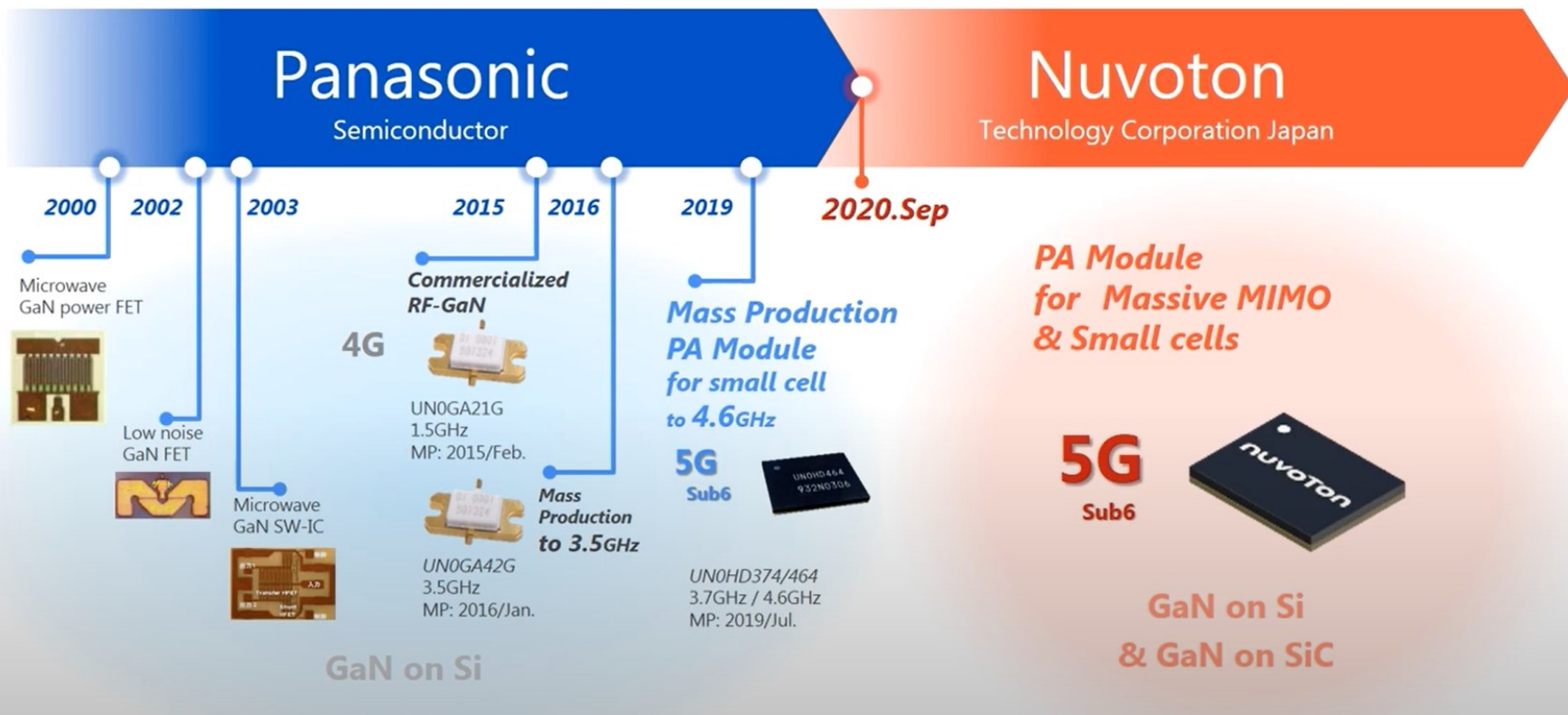


Nuvoton (Panasonic)



Nuvoton RF-GaN History

(former Panasonic Semiconductor)

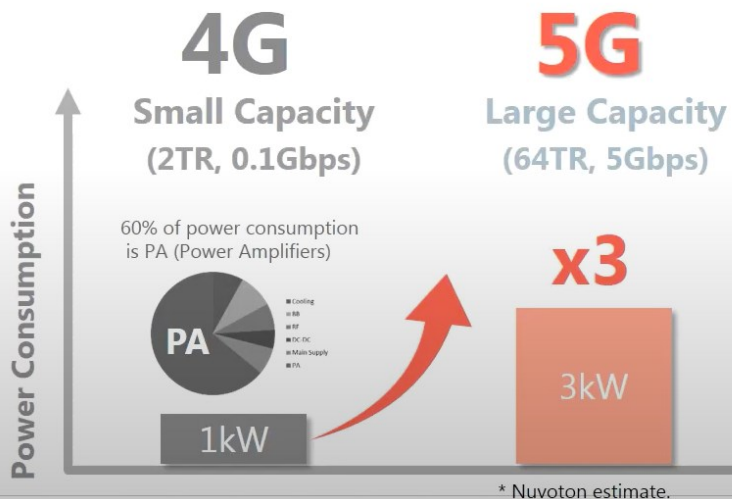


Proposal - ① Capacity

✓ 5G RAN issue

Large capacity requires
high power consumption

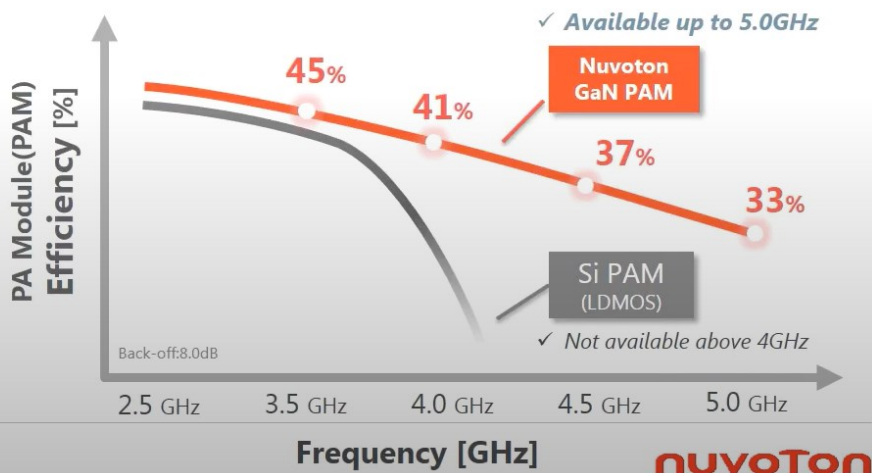
3x power consumption.



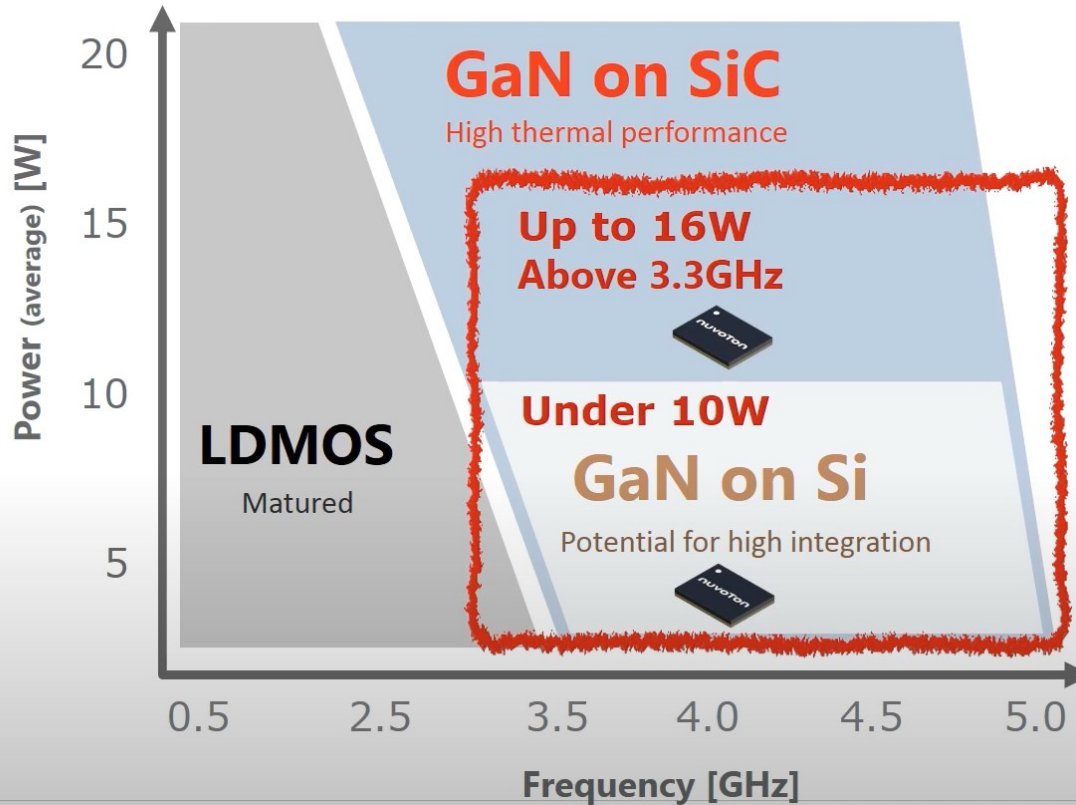
✓ Nuvoton Proposal

Reduce power consumption

Helps reduce power consumption.



RF-GaN Target Application



Massive MIMO



Area : 0.5 to 1.0 km

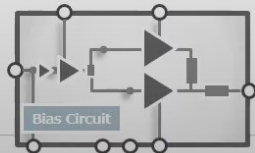
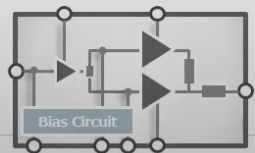
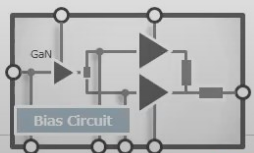
Small Cell / Local 5G



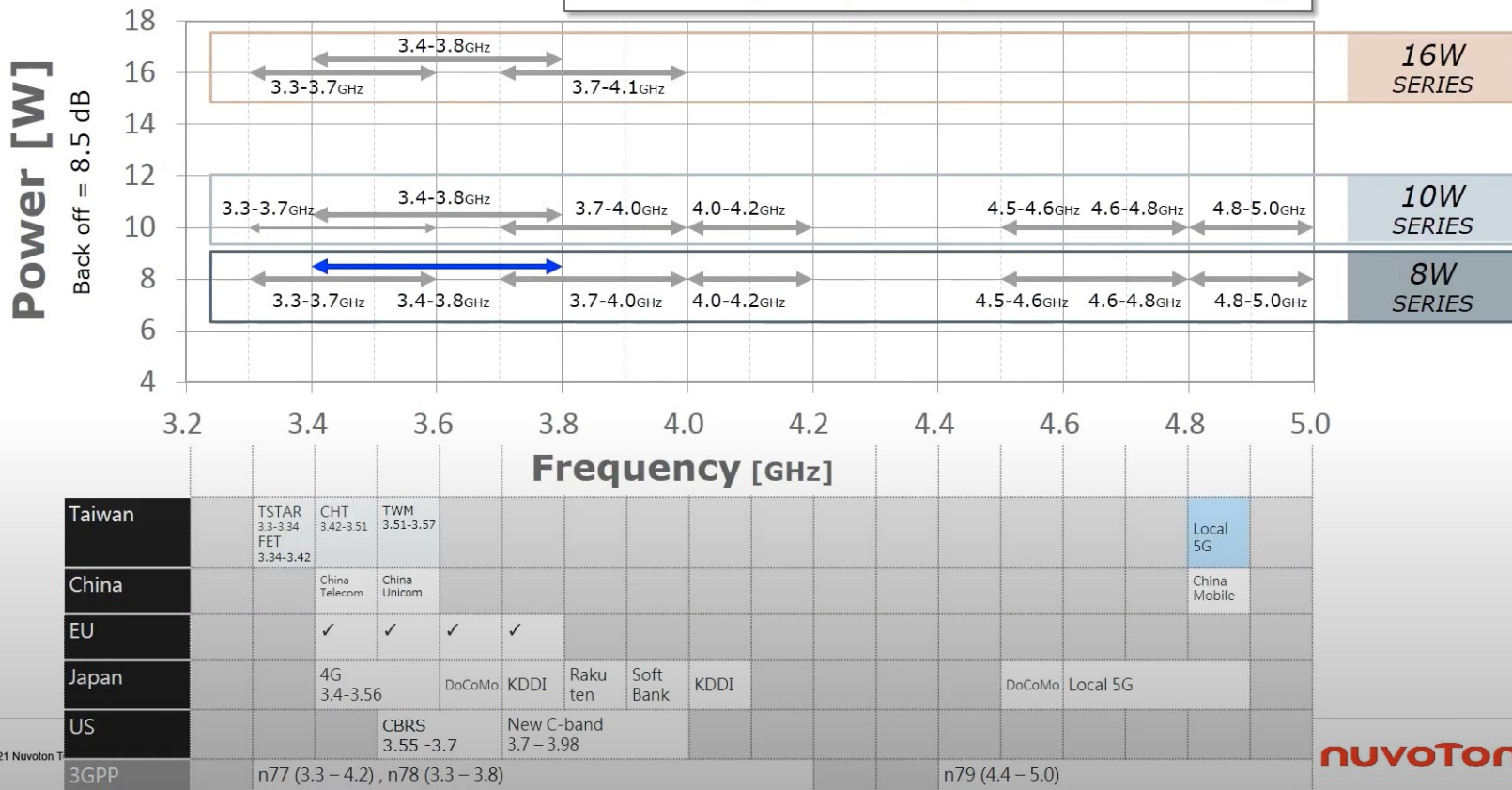
Area : 0.2 km

Nuvoton RF-GaN PA Module Line-up

2W for small cell, 8W to 16W for Massive MIMO.

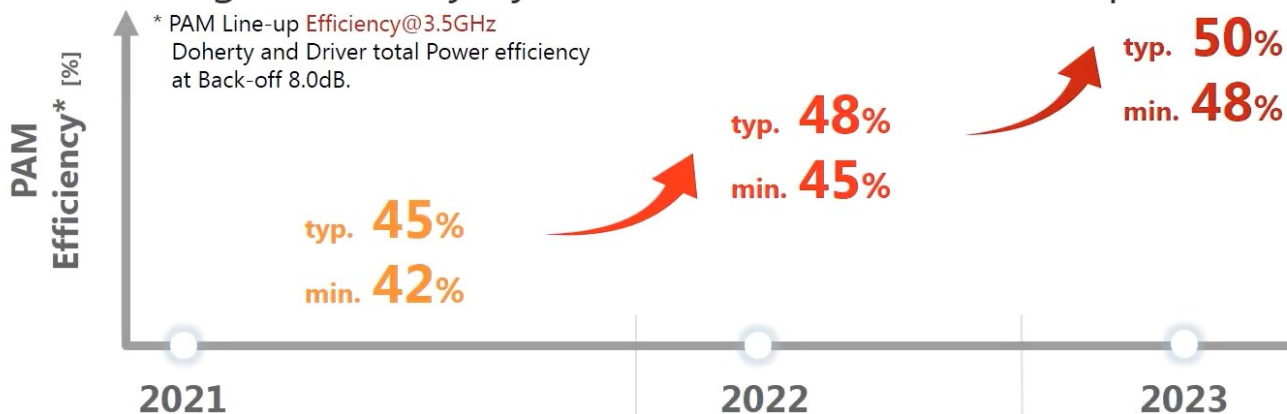
Application	Small Cell	Massive MIMO		
	5W/4TR, 10W/8TR	160W/32TR, 320W/64TR	200W/32TR, 400W/64TR	320W/32TR
Power (average)	2w (33dBm)	8w (39dBm)	10w (40dBm)	16w (42dBm)
Power (Saturation)	16W (42dBm)	63W (48dBm)	79W (49dBm)	126W (51dBm)
Module Size	8.0 x 10.0 mm	Pin compatible for each Power 8.0 x 12.0 mm		
Status	Mass Production	Under Development		
GaN	GaN on Si	GaN on Si		GaN on SiC
Vds	50V	28 V		
Block Diagram				

Product Line-up for Massive MIMO



Roadmap for efficiency improvement

High efficiency by GaN evolution and circuit update



GaN on Si
evolution

NGN19
Lg = 0.19 μm

Eff. +1%

NGN15
Lg = 0.15 μm

Eff. +2%

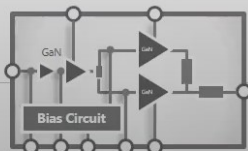
NGN10
Lg = 0.1 μm

NGN : Nuvoton RF-GaN
Lg : GaN gate length.



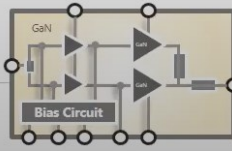
Circuit
update

Single Driver + Doherty



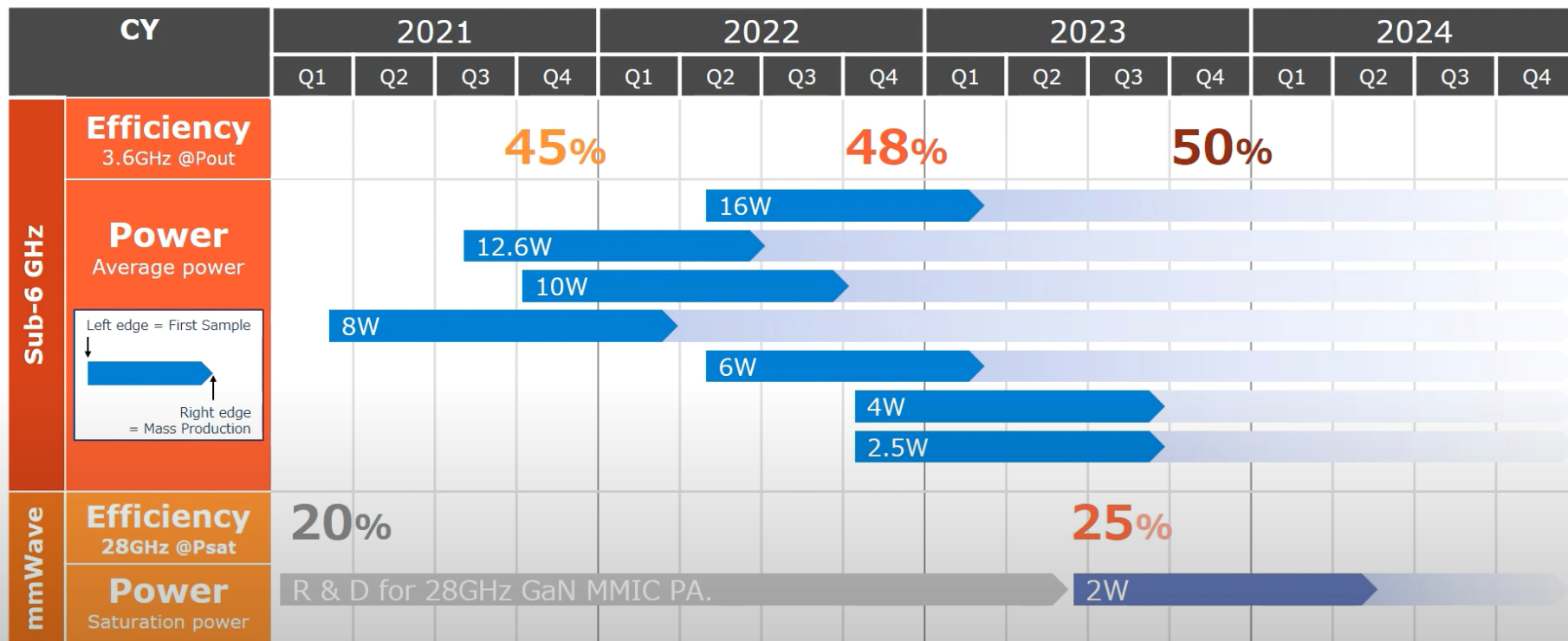
Eff. +2%

Twin Drivers + Doherty



nuvoTon

Roadmap for Product





Part of your life. Part of tomorrow.